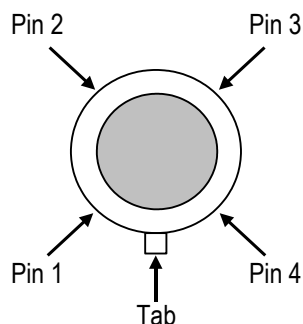


1. Pin Assignments

Figure 2. TO-39 (TO4) Pin Assignments for SGAS707 – Top View



2. Pin Descriptions

Table 1. TO-39 (TO4) Pin Descriptions

Note: See Figure 2 for the connections described below.

Pin Number	Name	Description
1	Heater +	Positive input for the V_H heater voltage supply
2	Sensor +	High-side of the resistive sensor element; positive input for sensing voltage V_C
3	Heater –	Negative (ground) input for the V_H heater voltage supply
4	Sensor –	Low-side of the resistive sensor element; connects to the middle of the resistor divider circuit and produces sensing voltage output (V_{OUT})

3. Sensor Specifications

Note: All measurements were made in dry gas at room temperature. Specifications are subject to change.

Table 2. Electrical Characteristics

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
P_H	Heater power consumption	$V_H = 3.5V$		400		mW
V_H	Recommended heater voltage	$T_{SENSOR} = 150^{\circ}C$		3.5		VDC
R_H	Heater resistance	At room temperature	28	30	32	Ω
V_C	Recommended sensing voltage		2.5		5.0	VDC
R_{500}	Resistance in 500ppm ethanol		5		500	k Ω
R_{100}/R_{900}	Resolution: Resistance in 100ppm Ethanol / Resistance in 900ppm		3.8			

Table 3. Temperature Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
T _{OP}	Sensor Operation Temperature	V _H = 3.5V		150		°C
T _{AMB}	Recommended Environmental Temperature Range		0		40	°C
T _{STOR}	Maximum Storage Temperature Range		-50		125	°C

The sensor is not intended for continuous operation above or below the environmental temperature specification, but exposure for short durations will not harm the sensor.

4. Sensor Characteristics

IDT's solid-state chemiresistive sensors are an advanced type of gas-sensitive resistor; i.e. they sense the presence of a target gas through a change in resistance of the sensing element. Most sensors exhibit reduced resistance as gas concentration increases, typically over several orders of magnitude across the sensing range.

Solid-state chemiresistive sensors show a reduced resistance with increasing gas concentration according to Equation 1:

$$R_S = A * C^{-\alpha} \quad \text{Equation 1}$$

where R_S is resistance, C is concentration, and A and α are constants. Although several refined versions of this equation are available for specific sensors or sensing materials, the fundamental resistance versus concentration relationship for all of IDT's n-type sensors follows Equation 1. Taking the log of both sides of the equation results in Equation 2:

$$\log(R_S) = \log(A) - \alpha * \log(C) \quad \text{Equation 2}$$

This shows that log resistance versus log concentration is linear.

An immediately observable consequence of Equation 1 is that sensor resistance will change rapidly at low concentrations and much less at high concentrations. This is illustrated in the following example:

$$R_{\text{GAS}_{10\text{ppm}}} = 20\text{k}\Omega$$

$$R_{\text{GAS}_{100\text{ppm}}} = 5\text{k}\Omega$$

$$A_{\text{GAS}} = 8.0 * 10^4$$

$$\alpha_{\text{air}} = 0.602$$

The non-logarithmic response plot shown in Figure 3 illustrates the fundamental challenge that must be addressed when measuring the resistance of chemiresistor sensors and relating these measurements to gas concentrations. Additional non-linear effects from the measurement circuitry exacerbate these challenges and must be understood in order to account for or eliminate these effects.